

Taiwan Semiconductor

15A, 60V Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ High efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

TYPICAL APPLICATIONS









Trench Schottky barrier rectifier is designed for high frequency
switched mode power supplies such as adapters, lighting, and
DC/DC converters.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free)

Terminal: Matte tin plated leads, solderable per J-STD-002

Meet JESD 201 class 1A whisker test

Polarity: As marked

Mounting torque: 0.56 Nm max.

Weight: 1.7 g (approximately)

MAXIMUM RATINGS AND ELEC	TRICAL C	HARACTER	RISTICS (T _a	= 25°C unl	ess otherwis	se noted)	
PARAMETER Maximum repetitive peak reverse voltage			SYMBOL TSF15L60CW		W	UNIT V	
			V _{RRM}	60			
Maximum average forward rectified	per device			15		A	
current	per diode		F(AV)	7.5			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode			I _{FSM}	80		А	
Voltage rate of change (Rated V _R)			dV/dt	10000		V/µs	
				MIN.	TYP.	MAX.	
	I _F =7.5A			-	0.61	0.70	- v
Instantaneous forward voltage per diode	I _F = 15A			-	0.79	0.88	
(Note1)	I _F =7.5A	– T _J = 125°C	V _F	-	0.59	0.68	
	I _F = 15A			-	0.74	0.83	
Maximum instantaneous reverse current per diode at rated reverse voltage $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$		1	100			μA	
		T _J = 125°C	I _R	50		mA	
Typical thermal resistance per diode			R _{θJC}	5			°C/W
Operating junction temperature range			TJ	- 55 to +150			°C
Storage temperature range			T _{STG}	- 55 to +150			°C

Note 1: Pulse test with pulse width = 300µs, 1% duty cycle



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ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
TSF15L60CW	CO	G	ITO-220AB	50 / Tube		

Note: Whole series with green compound

EXAMPLE PART NO.	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
TSF15L60CW C0G	TSF15L60CW	C0	G	Green compound

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



FIG. 3 TYPICAL REVERSE CHARACTERISTICS



FIG. 2 TYPICAL FORWARD CHARACTERISTICS



FIG. 4 TYPICAL JUNCTION CAPACITANCE



/ersion: A1603



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OUTLINE DIMENSION

ITO-220AB



DIM.	Unit	(mm)	Unit (inch)		
	Min	Max	Min	Max	
А	4.30	4.70	0.17	0.19	
В	2.50	3.16	0.10	0.12	
С	2.30	2.96	0.09	0.12	
D	0.46	0.76	0.02	0.03	
E	6.30	6.90	0.25	0.27	
F	9.60	10.30	0.38	0.41	
G	3.00	3.40	0.12	0.13	
Н	0.95	1.45	0.04	0.06	
I	0.50	0.90	0.02	0.04	
J	2.40	3.20	0.09	0.13	
К	14.80	15.50	0.58	0.61	
L	-	4.10	-	0.16	
М	12.60	13.80	0.50	0.54	
Ν	-	1.80	-	0.07	
0	2.41	2.67	0.09	0.11	

MARKING DIAGRAM



- = Specific Device Code
- = Green Compound
- W = Date Code
- = Factory Code



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